

ESE532: System-on-a-Chip Architecture

Day 17: March 22, 2017
Estimating Chip Area and Costs



Today

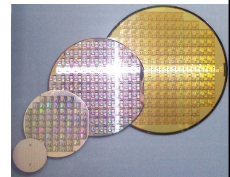
- Chip Costs from Area
- Chip Area
- Some Areas
 - CACTI – for modeling memories

Message

- First order:
 - Chip cost proportional to Area
 - Area = Sum(Area(Components))
- But appreciate the simplification:
 - Yield makes cost superlinear in area
 - I/O, Interconnect, infrastructure
 - Can make Area > Sum(Area(Components))

Wafer Cost

- Incremental cost of producing a silicon wafer is fixed for a given technology
 - Independent of the specific design
 - E.g. \$3,500
- Can fill wafer with copies of chip



By German Wikipediabiatch, original upload 7.
Okt 2004 by Stahlkocher de: Bild: Wafer 2 Zoll bis 8 Zoll.jpg,
CC BY-SA 3.0, <https://commons.wikimedia.org/w/index.php?curid=928106>

Preclass 1

- Rough cost per mm of silicon?
 - \$3500 for 300mm wafer

Implication

- Raw silicon die cost is roughly proportional to area
 - Larger the die, the fewer we get on the wafer

...but

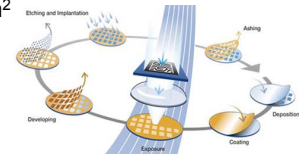
- Limits to how big we can make chips
 - Manufactures are prepared to create
 - Can be reliably manufactured
- ...and how small we can make chips
 - I/O pads
 - Cutting/handling/markings

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Imaging

- Limit to how large optical imaging supports
- Reticle – imagable region for photo lithography
 - Around 600mm^2



Source: <https://www.asmt.com/the-asmt-exposure-apparatus-is-the-most-expensive-and-complex-step-in-the-chip-fabrication-process-what-is-involved-in-the-lithography-business/> ja281437id=44709
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Yield

- Chips won't be manufactured perfectly
 - Dust particles can impact imaging
 - Manufacturing processes are statistical
- If chips must be defect-free,
 - larger chips are more likely to have defects than smaller chips

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Simple Yield Model

- Probability of a region being perfect
 - E.g. probability of one sq. mm being defect-free
- Chip yields if its entire area is defect free

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Chip Yield

- P = defect-free probability per sq. mm
- What is probability a chip of A sq. mm yields (symbolic) ?

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Preclass 2

- $P=0.99$
- Probability of yield for
 - 10 mm^2 , 50 mm^2 , 100 mm^2 , 500 mm^2

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Yielded Die

- For a yield rate, Y, how many raw die need to manufacture per yielded die?

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Preclass 3

- P=0.99
- Die cost for:
 - 10 mm², 50 mm², 100 mm², 500 mm²

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Yielded Die Cost

$$Cost = \frac{Raw}{Yield} = \frac{A * Cost / mm}{P^A}$$

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Yielded Die Cost

$$Cost = \frac{Raw}{Yield} = \frac{A * Cost / mm}{P^A}$$

- Ultimately exponential in Area
- Means
 - Expensive above knee in exponential curve
 - Close to linear below knee in curve
- E.g.
 - Below P^A=0.5
 - effect of Yield term is less than 2

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Design Dependent Cost

- P can be design dependent
 - More aggressive designs have higher defect rates
 - Can tune design to ease manufacturing
- Contrast with point that wafer manufacture cost independent of design

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Slightly Fuller Story

- Chip cost = die + test + package

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Test

- Testing costs proportional to test time
 - Time on expensive test unit
 - Depends on complexity of tests need to run
 - Can motivate spending silicon area on on-chip test structures to reduce
- Can dominate on small chips or complex testing

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Packaging

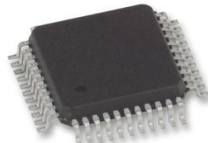
- Pay for density and performance

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Plastic Packages

- Simple plastic packages cheap
 - Limited number of pins
 - Limited to perimeter
 - Limited heat removal (few Watts)
 - Can be large (due to pins)
 - Higher inductance on pins



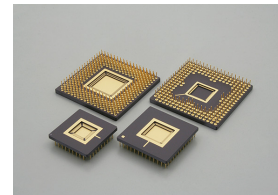
http://wiki.electroons.com/doku.php?id=ic_packages

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Ceramic Packages

- Better thermal characteristics
 - Add heat-sink, tolerate hotter chips
 - To 100 W
 - More pins



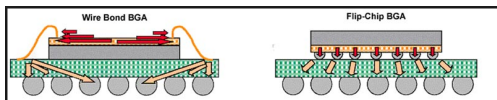
Source: https://www.ngkntk.co.jp/english/product/semiconductor_packages/htcc.html

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Flip Chip Packages

- Support Area-IO
 - More, denser pins
 - Smaller die if IO limited
 - Lower inductances
 - Smaller packaged chip

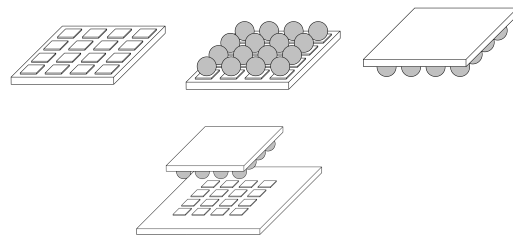


Source: <http://mantravlsi.blogspot.com/2014/10/flip-chip-and-wire-bonding.html>

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Flip Chip I/O

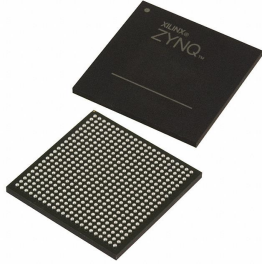


Source: https://en.wikipedia.org/wiki/Flip_chip

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Zynq Land Grid Package



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Don't Forget NRE

- This is all about recurring costs

$$Cost = RecurringCost + \frac{NRE}{NumParts}$$

- NRE
 - Mask costs in millions
 - Design costs in 10s to 100s of millions

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Price vs. Cost

- ...and this is all about **cost**
 - What it takes to manufacture
- Price
 - What people will pay for it
- Profit = Price - Cost

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Area

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Area

- Simple story
 - Sum up component areas

$$A = \sum_i A_i$$

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Too Simplistic

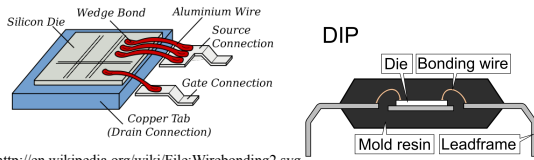
- Area may be driven by
 - I/O
 - Interconnect
- Will need to pay for infrastructure
 - Clocking, Power

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I/O Pads

- Must go on edge for wire bonding
 - Esp. for cheap packages



Src: <http://en.wikipedia.org/wiki/File:Wirebonding2.svg>

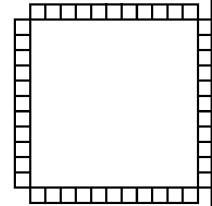
Source: https://commons.wikimedia.org/wiki/File:DIP_package_sideview.PNG

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Pad Ring

- Pads must go on side of chip
- Pad spacing large to permit bonding
- I/O pads may set lower bound on chip size



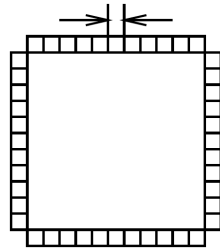
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Preclass 4

- 400 pads
- 25µm pad spacing
- Minimum chip dimensions?

pad pitch



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I/O Limits

- Perimeter grows as 4s
- Area grows as s²
- Area grows (NumIO/4)²
- IO may drive chip area

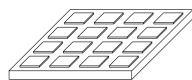
$$A = \text{Max} \left(\left(\sum_i A_i \right), \left(\frac{\text{NumIO}}{4} \right)^2 \right)$$

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Area I/O

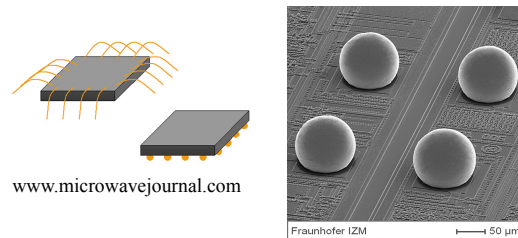
- Put I/O in grid over chip
- I/O pads still large and take up space
- Avoid perimeter scaling
- Requires more expensive flip-chip package



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Flip Chip, Area IO



www.microwavejournal.com

http://www.izm.fraunhofer.de/en/abteilungen/high_density_interconnectwaferlevelpackaging/arbeitsgebiete/arbeitsgebiet1.html

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Interconnect

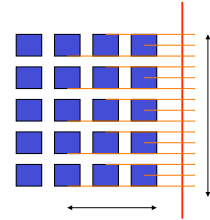
- Wires take up space
- Similar issue to pad I/O
 - Wires crossing into region grow as perimeter
 - Logic inside grows as area
- Region size may be dictated by wires entering/leaving

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Wiring Requirements

- Wires 50nm pitch
- Gates 500nm tall
- How many gates per row can provide outputs before saturate edge?
- What if want more outputs to exit across edge?

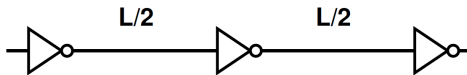


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Interconnect

- Long wires need buffering
- Buffers take up space
 - Weren't in simple accounting of logic and memory blocks



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Infrastructure: Clocking

- PLL (Phased-Lock-Loop) to generated lock
- Clock drivers are big (drive big load)
- Need buffering all over chip

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Infrastructure: Power

- Need many I/O Pads
 - Carry current
 - Keep inductance low
- Wires to distribute over chip
- Maybe
 - Capacitance to stabilize power
 - Voltage converters

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$$\text{Area} \quad A = \sum_i A_i$$

- Mostly sum of components, but...
- Area may be driven by
 - I/O
 - Interconnect
- Will need to pay for infrastructure
 - Clocking, Power

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Some Areas

Processor Areas

- ARM Cortex A9 about 1mm^2 in 28nm
 - Zynq processor
 - SuperScalar core
- A5 (scalar) about 0.25mm^2
- A15 (higher performance) about 3mm^2

Zynq Compute Blocks

Crude estimate, including interconnect

- 2000 6-LUTs per sq. mm
- DSP Block ~ 0.1 sq. mm

CACTI

- Standard program for modeling memories and caches
 - More sophisticated version of the simple modeling we've been doing

CACTI Parameters

- Technology
- Capacity
- Output Width
- Ports
- Cache ways

Example Output

```
- Total cache size (bytes): 32768
  Number of banks: 1
  Associativity: 4
  Block size (bytes): 64
  Read/write Ports: 1
  Read ports: 0
  Write ports: 0
  Technology size (nm): 32

  Access time (ns): 1.09421
  Cycle time (ns): 1.25458
  Total dynamic read energy per access (nJ): 0.0234295
  Total dynamic write energy per access (nJ): 0.018806
  Total leakage power of a bank without power gating, including its network (mW): 0.000000
  Cache height x width (mm): 0.152304 x 0.523289
```